

MMBT2222A

NPN GENERAL PURPOSE TRANSISTOR

VOLTAGE 40 Volt **POWER** 300 mWatt

SOT-23

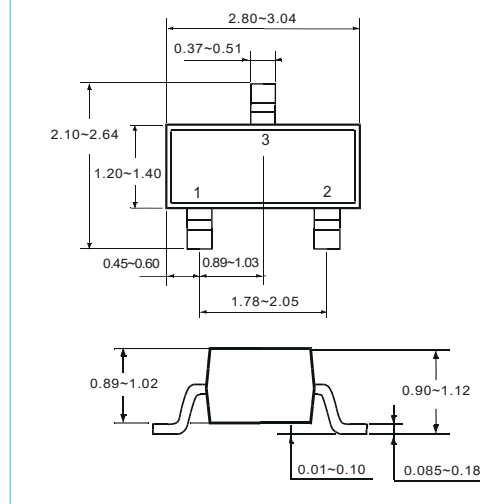
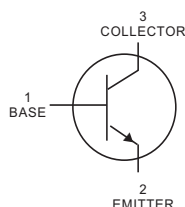
Unit:mm

FEATURES

- NPN epitaxial silicon, planar design
- Epitaxial planar die construction
- Complementary PNP Type available(MMBT2907A)
- Lead free in compliance with EU RoHS
- Marking: 1P

MECHANICAL DATA

- Case Material: Molded Plastic.
- UL Flammability Classification Rating 94V-0



MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Units
Collector - Emitter Voltage	V _{CEO}	40	V
Collector - Base Voltage	V _{CBO}	75	V
Emitter - Base Voltage	V _{EBO}	6	V
Collector Current - Continuous	I _C	600	mA
Collector Dissipation	P _C	300	mW
Thermal resistance junction to ambient	R _{θJA}	417	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55~+150	°C

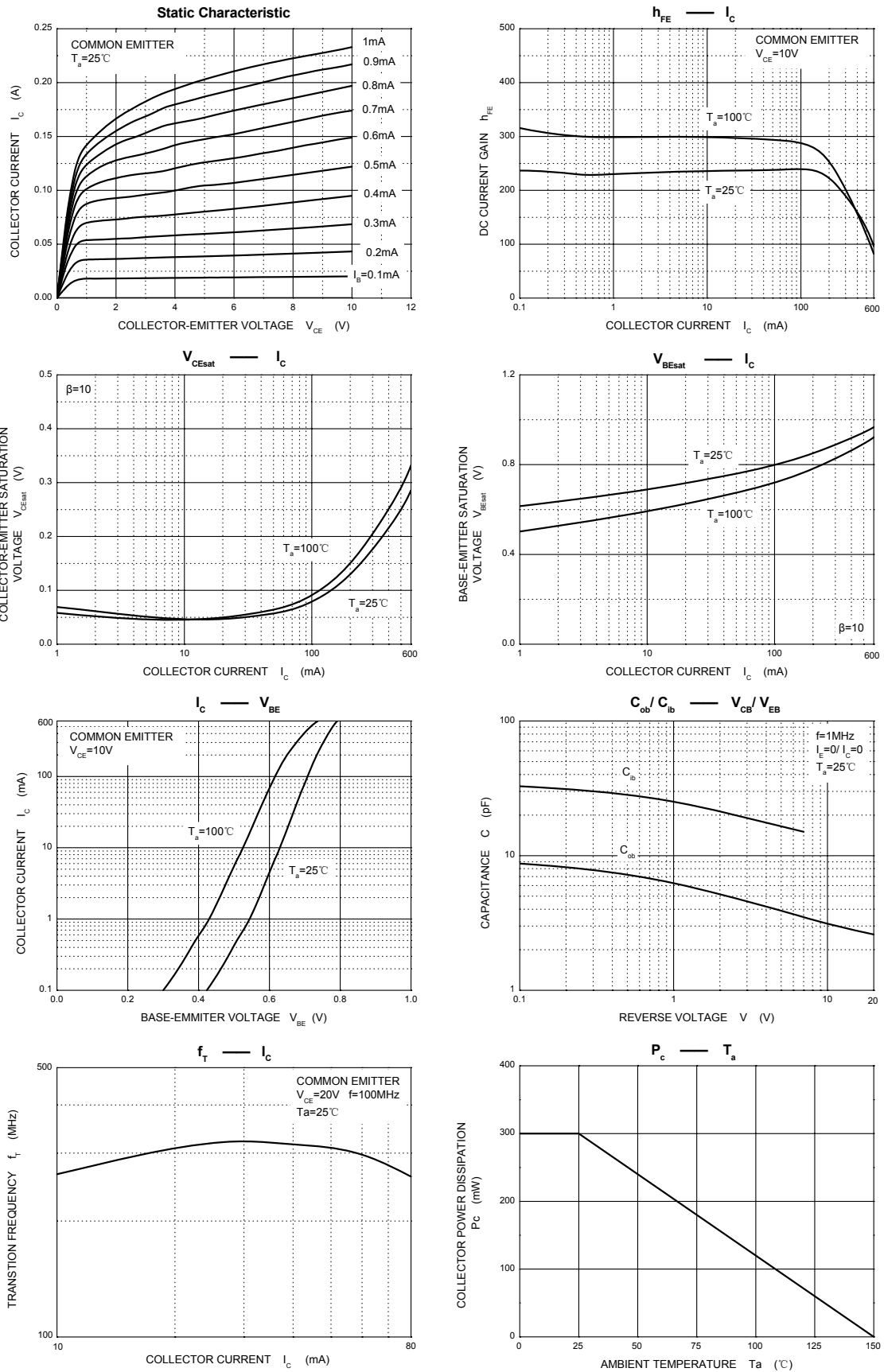
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ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}$, $I_E=0$	75		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}$, $I_B=0$	40		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}$, $I_C=0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB}=60\text{V}$, $I_E=0$		10	nA
Collector cut-off current	I_{CEX}	$V_{CE}=30\text{V}$, $V_{BE(off)}=3\text{V}$		10	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=3\text{V}$, $I_C=0$		100	nA
DC current gain	h_{FE1}	$V_{CE}=10\text{V}$, $I_C=150\text{mA}$	100	300	
	h_{FE2}	$V_{CE}=10\text{V}$, $I_C=0.1\text{mA}$	40		
	h_{FE3}	$V_{CE}=10\text{V}$, $I_C=500\text{mA}$	42		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$ $I_C=150\text{mA}$, $I_B=15\text{mA}$		1.0 0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$ $I_C=150\text{mA}$, $I_B=15\text{mA}$		2.0 1.2	V
Transition frequency	f_T	$V_{CE}=20\text{V}$, $I_C=20\text{mA}$, $f=100\text{MHz}$	300		MHz
Delay Time	t_d	$V_{CC}=30\text{V}$, $V_{BE}=0.5\text{V}$		10	nS
Rise Time	t_r	$I_C=150\text{mA}$, $I_{B1}=15\text{mA}$		25	nS
Storage Time	t_s	$V_{CC}=30\text{V}$, $I_C=150\text{mA}$		225	nS
Fall Time	t_f	$I_{B1}=I_{B2}=15\text{mA}$		60	nS

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Typical Characteristics

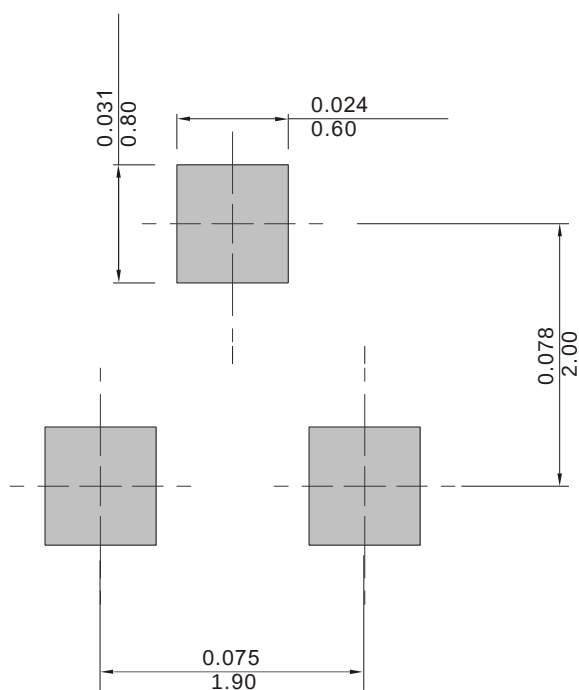


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MOUNTING PAD LAYOUT

SOT-23

Unit:Inch(mm)



ORDER INFORMATION

- Packing information

Part Number	Case	Reel Size	QUANTITY
MMBT3904	SOT-23	7 Inch	3000